TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXR162652FT

Low-Voltage 16-Bit Bus Transceiver/Register with 3.6-V Tolerant Inputs and Outputs

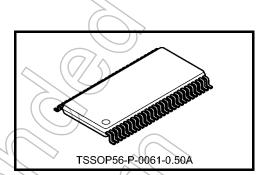
The TC74VCXR162652FT is a high-performance CMOS 16-bit bus transceiver/register. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to $3.6\ V.$

This device is bus transceiver with 3-state outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the internal registers.

The $26-\Omega$ series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

Features (Note)

- 26-Ω series resistors on outputs
- Low-voltage operation: V_{CC} = 1.8 to 3.6 V
- High-speed operation: $t_{pd} = 3.8 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

 $t_{pd} = 4.9 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$

 $t_{pd} = 9.8 \text{ ns (max) (VCC} = 1.8 \text{ V)}$

• Output current: $I_{OH}/I_{OL} = \pm 12 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$

 $: I_{OH}/I_{OL} = \pm 8 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 4 \text{ mA (min)} (V_{CC} = 1.8 \text{ V})$

- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V

Human body model $\geq \pm 2000 \text{ V}$

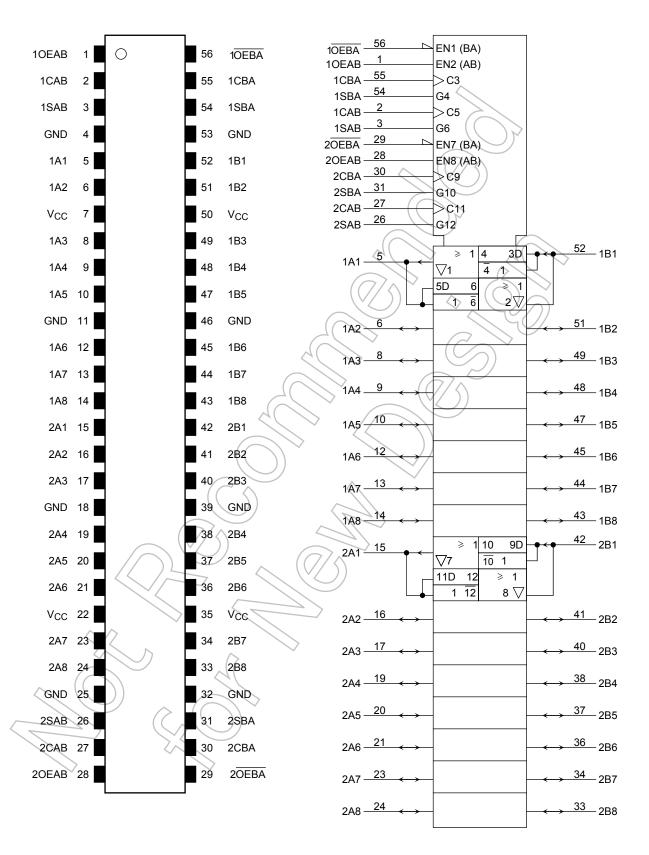
- Package: TSSOP
- Bidirectional interface between 2.5 V and 3.3 V signals.
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input level fixed by means of pull-up or pull-down resistors.

Pin Assignment (top view)

IEC Logic Symbol



Truth Table

		Control Inputs Bus		ıs	Function			
OEAB	OEBA	CAB	CBA	SAB	SBA	Α	В	Function
		X*	X*	Х	Х	Input	Input	The output functions of A and B Busses are
L	н	^	^	^	^	Z	Z	disabled.
L	П			X	X	X	X	Both A and B Busses are used as inputs to the internal flip-flops. Data on the Bus will be stored on the rising edge of the Clock.
						Input	Output	
		X*	X*	L	X	L	L <	The data on the A bus are displayed on the B bus.
						Н	Н	
		_	X*	L	Х	L	L	The data on the A bus are displayed on the B Bus, and are stored into the A storage
Н	Н		^*	L	^	Н	H	flip-flops on the rising edge of CAB.
		X*	X*	Н	Х	х	Qn	The data in the A storage flop-flops are displayed on the B Bus.
		√				L ((//_\)	The data on the A Bus are stored into the A storage flip-flops on the rising edge of CAB,
			X*	Н	Х	H	#	and the stored data propagate directly onto the B Bus.
					/	Output	Input	
		X*	X*	X	L	À	L	The data on the B Bus are displayed on the A bus.
						H	Н	$(/ / \hat{\gamma})$
		X*		Х	4	L		The data on the B Bus are displayed on the A Bus, and are stored into the B storage
L	L	Λ				. H <	Ŧ	flip-flops on the rising edge of CBA.
		X*	X*	x	Ī	Qn	X	The data in the B storage flip-flops are displayed on the A Bus.
			•	((\		L <	L	The data on the B Bus are stored into the B storage flip-flops on the rising edge of CBA,
		X*		X) н	H	H	and the stored data propagate directly onto the A Bus.
				$\langle \gamma \rangle$		Output	Output	
					\ (I	7/4	-201701	The data in the A storage flop-flops are
Н	L	X*	X*	7 H	H	Qn	Qn	displayed on the B Bus, and the data in the B storage flop-flops are displayed on the A.
				(- ' ' ' '

X: Don't care

Z: High impedance

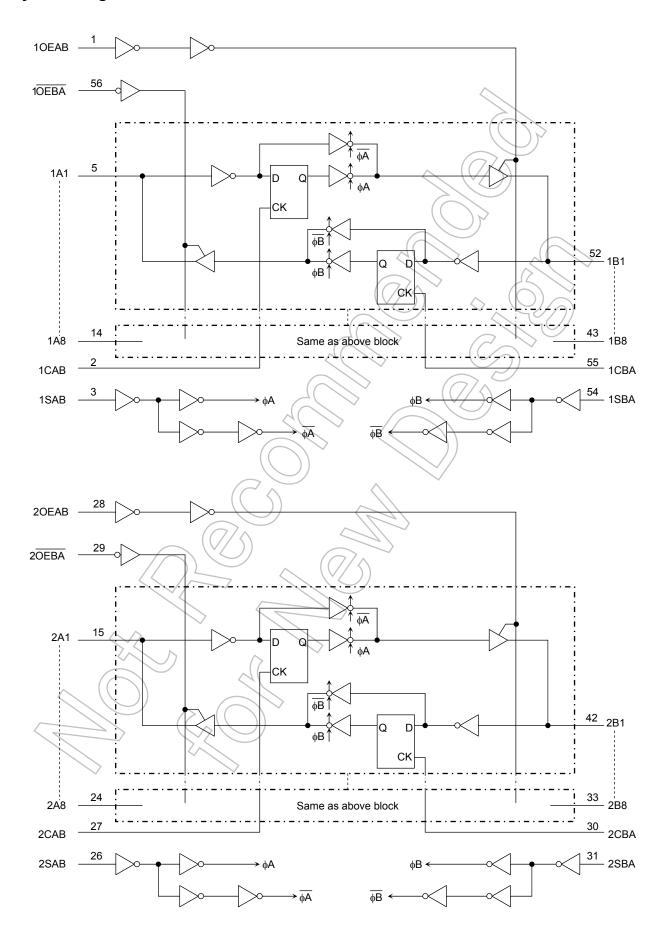
Qn: The data stored into the internal flip-flops by most recent low to high transition of the clock inputs.

3

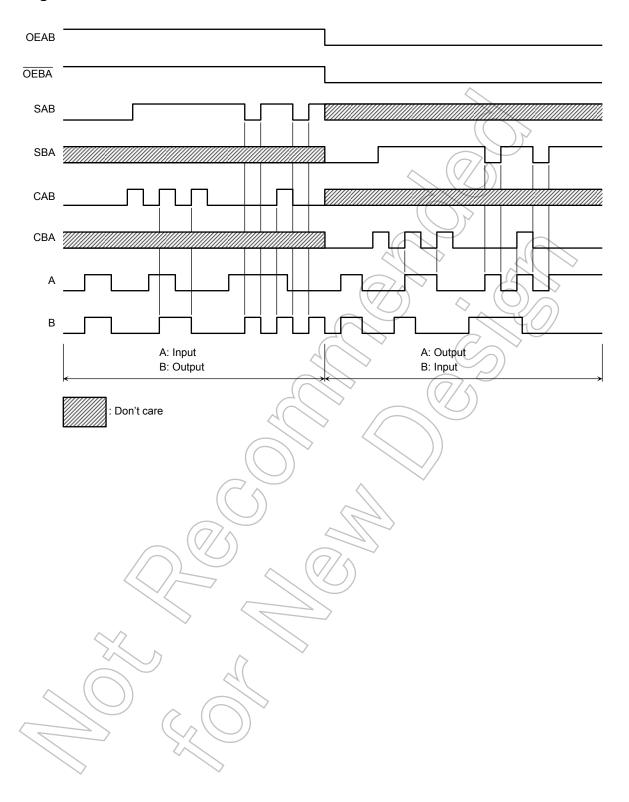
*: The clocks are not internally gated with either OEAB or OEBA.

Therefore, data on the A and/or B busses may be clocked into the storage flip-flops at any time.

System Diagram



Timing Chart



5

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5 to 4.6	V	
DC input voltage (CAB, CBA, SAB, SBA, OEAB, OEBA)	V _{IN} -0.5 to 4.6		V	
DC bus I/O voltage	V _{I/O}	-0.5 to 4.6 (Note 2)	V	
Do bus no voltage	V 1/O	-0.5 to V_{CC} + 0.5 (Note 3)	_	
Input diode current	I _{IK}	-50	mA	
Output diode current	lok	±50 (Note 4)	mA	
DC output current	lout	±50	mA	
Power dissipation	P_{D}	400	mW)	
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	-65 to 150	\%C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	Vcc	1.8 to 3.6 1.2 to 3.6 (Note 2)	٧	
Input voltage (CAB, CBA, SAB, SBA, OEAB, OEBA)	VIN	-0.3 to 3.6	V	
Bus I/O voltage	V _{I/O}	0 to 3.6 (Note 3)	V	
Bus i/O voltage	V1/O	0 to V _{CC} (Note 4)	V	
	7(±12 (Note 5)		
Output current	IOH/IOL	±8 (Note 6)	mA	
		±4 (Note 7)		
Operating temperature	Topr	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: Data retention only

Note 3: OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$

Note 7: $V_{CC} = 1.8 \text{ V}$

Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, $2.7 \text{ V} < \text{V}_{\text{CC}} \le 3.6 \text{ V})$

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	_	_	2.7 to 3.6	2.0	_	V
input voitage	L-level	V _{IL}	_	_	2.7 to 3.6	-	0.8	V
				$I_{OH} = -100 \mu A$	2.7 to 3.6	V _{CC} - 0.2		
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	//2.7	2.2	_	
				$I_{OH} = -8 \text{ mA}$	3.0	2.4		V
Output voltage				I _{OH} = -12 mA	3.0	2.2	_	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 100 \mu\text{A}$	2.7 to 3.6		0.2	
				I _{OL} = 6 mA	2.7	#	0.4	
				I _{OL} = 8 mA	3.0	_/	0.55	
				I _{OL} = 12 mA	3.0(()	0.8	
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 3.6 V		2.7 to 3.6	K)	±5.0	μΑ
3-state output OFF state current		l _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		2.7 to 3.6)	±10.0	μА
Power-off leakage current		l _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V	\$ 6			10.0	μА
Ouisseent auguly augrant		Icc	V _{IN} = V _{CC} or GND		2.7 to 3.6		20.0	
Quiescent supply c	Quiescent supply current		V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.7 to 3.6	_	±20.0	μΑ
Increase in I _{CC} per	input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristics		Symbol	Test Co	Test Condition		Min	Max	Unit
		(7/			V _{CC} (V)		Max	01
Input voltage	H-level	ViH			2.3 to 2.7	1.6	_	V
input voitage	L-level	VIL))	2.3 to 2.7	_	0.7	V
		>		I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -4 \text{ mA}$	2.3	2.0	_	V
	N n			$I_{OH} = -6 \text{ mA}$	2.3	1.8	_	
Output voltage				$I_{OH} = -8 \text{ mA}$	2.3	1.7	_	
			VIN = VIH or VIL	I _{OL} = 100 μA	2.3 to 2.7	_	0.2	
	L-level	Vol		I _{OL} = 6 mA	2.3	_	0.4	
	(I _{OL} = 8 mA	2.3	_	0.6	
Input leakage curren	t	JIN	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μΑ
3-state output OFF state current		loz	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 3.6 V		2.3 to 2.7	_	±10.0	μА
Power-off leakage current I _{OFF}		loff	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μΑ
Quiescent supply current		loo	V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	
Quiescent supply cu	Helit	Icc	V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.3 to 2.7		±20.0	μА

DC Characteristics (Ta = -40 to 85°C, 1.8 V \leq V $_{CC}$ < 2.3 V)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit	
Input voltage	H-level	V _{IH}	_	_		0.7 × V _{CC}	_	V	
input voitage	L-level	V _{IL}	_		1.8 to 2.3	_	0.2 × V _{CC}	V	
H-level		VoH	V _{IN} = V _{IH} or V _{II}	I _{OH} = -100 μA	1.8	VCC - 0.2			
Output voltage		011		I _{OH} = -4 mA	71.8	1.4	_	V	
	L-level \	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8	_	0.2]	
				I _{OL} = 4 mA	1.8	_	0.3		
Input leakage currer	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.8		±5.0	μΑ	
3-state output OFF state current		loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$	4	1.8	<u> </u>	±10.0	μА	
Power-off leakage current		l _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0	7-/	> 10.0	μΑ	
Quiescent supply current		la a	V _{IN} = V _{CC} or GND		1.8		20.0	^	
Quiescent supply cu	IIICIII	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6$	V	1.8	9	±20.0	μА	

8

TOSHIBA

AC Characteristics (Ta = –40 to 85°C, input: $t_r = t_f$ = 2.0 ns, C_L = 30 pF, R_L = 500 Ω) (Note 1)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
			1.8	100	_	
Maximum clock frequency	f _{max}	Figure 1, Figure 3	2.5 ± 0.2	200	_	MHz
			3.3 ± 0.3	250	_	
Propagation delay time	.		1.8	1.5	9.8	
(An, Bn-Bn, An)	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	0.8	4.9	ns
(אוו, טוו-טוו, אוו)	^t pHL		3.3 ± 0.3	0.6	3.8	
Propagation delay time	t-111		1.8	1.5	9.8	
(CAB, CBA-Bn, An)	t _{pLH}	Figure 1, Figure 3	2.5 ± 0.2	0.8	5.8	ns
(6/15, 65/15/11, 711)	ФПС		3.3 ± 0.3	0.6	4.1	
Propagation delay time	tolli	4(>	1.8	1(5	9.8	
(SAB, SBA-Bn, An)	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	0.8	5.8	ns
(0.0, 00.0, 1.0,	·pi iL	$(\vee / 3)$	3.3 ± 0.3	0.6	4.4	
Output enable time	t _{pZL}		1.8	45/	9.8	
(OEAB, OEBA -An, Bn)		Figure 1, Figure 4, Figure 5	2.5 ± 0.2	0.8	5.9	ns
(OEND, OEDIT FIII, DII)		4(>)	3.3 ± 0.3	0.6	4.3	
Output disable time	t _{pLZ}		1.8	1.5	9.4	ns
(OEAB, OEBA -An, Bn)		Figure 1, Figure 4, Figure 5	2.5 ± 0.2	0.8	5.2	
(02.12, 022, 11.1, 21.1)			3.3 ± 0.3	0.6	4.5	
	t _{w (H)}		1.8	4.0	_	
Minimum pulse width		Figure 1, Figure 3	2.5 ± 0.2	1.5	_	ns
	t _{w (L)}		3.3 ± 0.3	1.5	_	
			1.8	2.5	_	
Minimum setup time	ts	Figure 1, Figure 3	2.5 ± 0.2	1.5	_	ns
	(\bigcirc)		3.3 ± 0.3	1.5	_	
		$\langle \langle \langle / \rangle \rangle$	1.8	1.0	_	
Minimum hold time	th	Figure 1, Figure 3	2.5 ± 0.2	1.0	_	ns
			3.3 ± 0.3	1.0	_	
$\langle \rangle \rangle$	tocky		1.8	_	0.5	ns
Output to output skew	tosLH	(Note 2)	2.5 ± 0.2	_	0.5	
	tosHL		3.3 ± 0.3	_	0.5	

9

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}, C_L = 30 \text{ pF}, R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition				Unit
				V _{CC} (V)		
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	0.15	
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	0.25	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	0.35	ļ
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	-0.15	
Quiet output minimum dynamic V _{OI}	02.	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	-0.25	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	-0.35	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	1.55	
Quiet output minimum dynamic V _{OH}	V _{OHV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	2.05	V
17 OH		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	2.65	

Note: Parameter guaranteed by design.

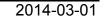
Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	(OEAB, OEBA, CAB, CBA, SAB, SBA)	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	An, Bn	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C_{PD}	f _{IN} = 10 MHz (Note)	1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$



AC Test Circuit

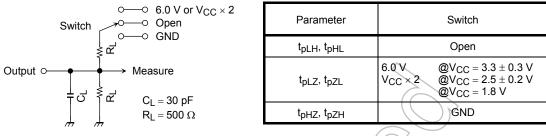


Figure 1 **AC Waveform** t_r 2.0 ns t_f 2.0 ns $\mathcal{V}_{\mathsf{IH}}$ Input (An, Bn, GND SAB, SBA) Von Output V_{M} (Bn, An) VOL ^tpHL tpLH Figure 2 tpLH, tpHL t_f 2.0 ns t_r 2.0 ns V_{IH} 90% Input V_{M} (CAB, CBA) 10% GND $t_w(H)$ $t_{W}\left(L\right)$ - V_{IH} Input V_{M} (An, Bn) - GND t_s (H) $t_h(H)$ t_s (L) th (L) V_{OH} Output (Bn, An) - V_{OL}

Figure 3 t_{pLH}, t_{pHL}, t_w, t_s, t_h

tpLH

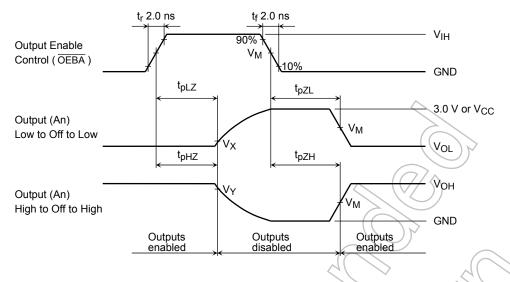


Figure 4 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

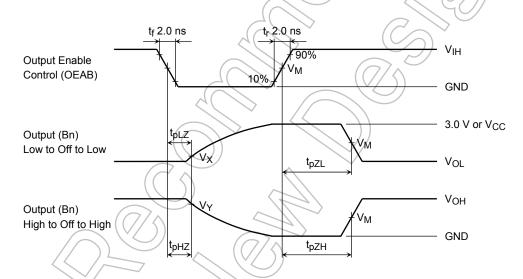
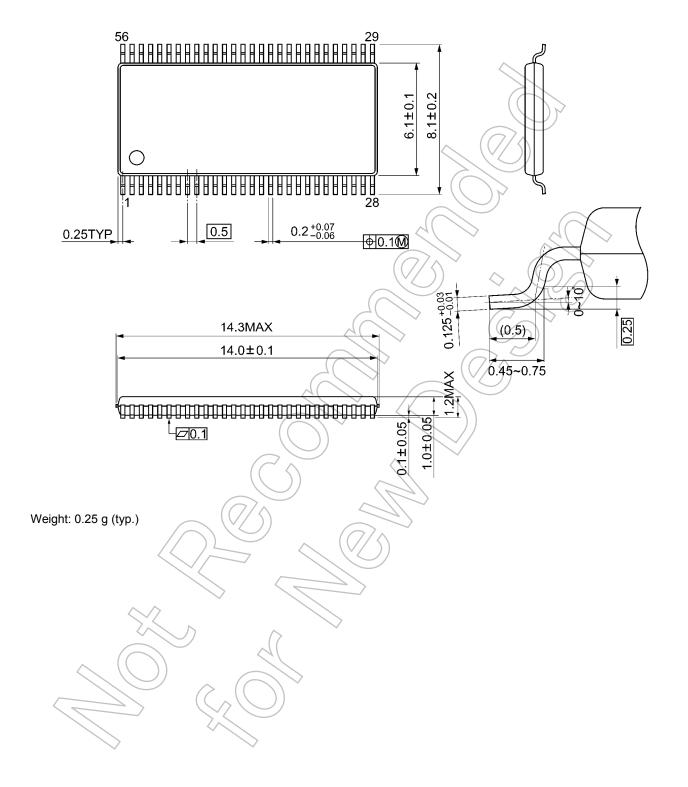


Figure 5 tpLz, tpHz, tpZL, tpZH

Symbol	Vcc							
Symbol	$3.3 \pm 0.3 \text{ V}$	$2.5\pm0.2\textrm{V}$	1.8 V					
VIH	2.7 V	V _{CC}	V _{CC}					
\nearrow V _M $(($	1.5 V	V _{CC} /2	V _{CC} /2					
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V					
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V					

Package Dimensions

TSSOP56-P-0061-0.50A Unit: mm



RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for
 automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions,
 safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
 Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.